

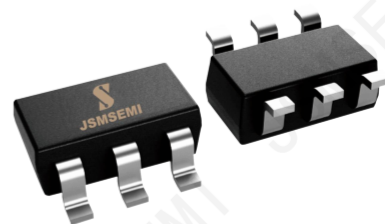
1、General Description

The 74LVC2G14 provides two inverting buffers with Schmitt-trigger input. It is capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

The inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device in a mixed 3.3V and 5V environment. Schmitt-trigger action at the inputs makes the circuit tolerant of slower input rise and fall time.

Features:

- Wide supply voltage range from 1.65V to 5.5V
- 5V tolerant inputs for interfacing with 5V logic
- $\pm 24\text{mA}$ output drive ($V_{CC}=3.0\text{V}$)
- CMOS low power consumption
- Direct interface with TTL levels
- Unlimited rise and fall times
- Specified from -40°C to $+125^{\circ}\text{C}$
- Packaging information: SOT-23-6/SOT-363



2、Block Diagram And Pin Description2

.1、Block Diagram

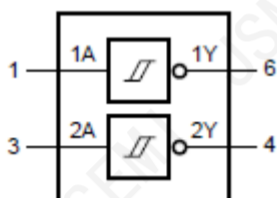


Figure 1. Logic symbol



Figure 2. IEC logic symbol

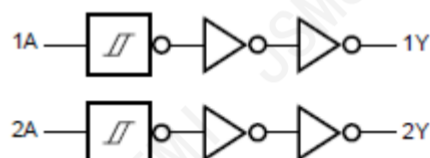
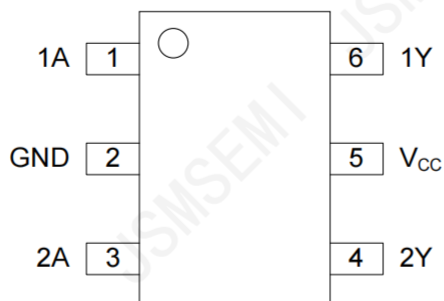


Figure 3. Logic diagram

Ordering Information

Order number	Package	Marking	Operation Temperature Range	MSL Grade	Ship, Quantity	Green
74LVC2G14GV-JSM	SOT-23-6	APXX	-40 to 125°C	3	T&R,3000	Rohs
74LVC2G14GW,125-JSM	SOT-363	APXX	-40 to 125°C	3	T&R,3000	Rohs

2.2、Pin Configurations



SOT23-6/SOT363

2.3、Pin Description

Pin No.	Pin Name	Description
1	1A	data input
2	GND	ground (0V)
3	2A	data input
4	2Y	data output
5	V _{CC}	supply voltage
6	1Y	data output

2.4、Function Table

Input	Output
nA	nY
L	H
H	L

Note: H=HIGH voltage level; L=LOW voltage level.

3、Electrical Parameter

3.1、Absolute Maximum Ratings

(Voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Max.	Unit
supply voltage	V_{CC}	-	-0.5	+6.5	V
input voltage	V_I	-	-0.5	+6.5	V
output voltage	V_O	Active mode	-0.5	$V_{CC}+0.5$	V
		Power-down mode; $V_{CC}=0V$	-0.5	+6.5	V
input clamping current	I_{IK}	$V_I < 0V$	-50	-	mA
output clamping current	I_{OK}	$V_O > V_{CC}$ or $V_O < 0V$	-	± 50	mA
output current	I_O	$V_O=0V$ to V_{CC}	-	± 50	mA
supply current	I_{CC}	-	-	100	mA
ground current	I_{GND}	-	-100	-	mA
storage temperature	T_{stg}	-	-65	+150	°C
total power dissipation	P_{tot}	-	-	250	mW
soldering temperature	T_L	10s	260		°C

3.2、Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	1.65	-	5.5	V
input voltage	V_I	-	0	-	5.5	V
output voltage	V_O	Active mode	0	-	V_{CC}	V
		Power-down mode; $V_{CC}=0V$	0	-	5.5	V
ambient temperature	T_{amb}	-	-40	-	+125	°C

3.3、Electrical Characteristics

3.3.1、DC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level output voltage	V _{OH}	V _I = V _{T+} or V _{T-}	I _O =-100uA; V _{CC} =1.65V to 5.5V	V _{CC} - 0.1	-	-	V
			I _O =-4mA; V _{CC} =1.65V	1.2	-	-	V
			I _O =-8mA; V _{CC} =2.3V	1.9	-	-	V
			I _O =-12mA; V _{CC} =2.7V	2.2	-	-	V
			I _O =-24mA; V _{CC} =3.0V	2.3	-	-	V
			I _O =-32mA; V _{CC} =4.5V	3.8	-	-	V
LOW-level output voltage	V _{OL}	V _I = V _{T+} or V _{T-}	I _O =100uA; V _{CC} =1.65V to 5.5V	-	-	0.10	V
			I _O =4mA; V _{CC} =1.65V	-	-	0.45	V
			I _O =8mA; V _{CC} =2.3V	-	-	0.30	V
			I _O =12mA; V _{CC} =2.7V	-	-	0.40	V
			I _O =24mA; V _{CC} =3.0V	-	-	0.55	V
			I _O =32mA; V _{CC} =4.5V	-	-	0.55	V
input leakage current	I _I	V _I =5.5V or GND; V _{CC} =0V to 5.5V		-	-	±1	uA
power-off leakage current	I _{OFF}	V _I or V _O =5.5V; V _{CC} =0V		-	-	±2	uA
supply current	I _{CC}	V _I =5.5V or GND; I _O =0A; V _{CC} =1.65V to 5.5V		-	-	4	uA
additional supply current	ΔI _{CC}	V _I =V _{CC} -0.6V; I _O =0A; V _{CC} =2.3V to 5.5V		-	-	500	uA
input capacitance	C _I	V _{CC} =3.3V; V _I =GND to V _{CC}		-	3.5	-	pF

Note: All typical values are measured at maximum V_{CC} and $T_{amb} = 25^{\circ}\text{C}$.

3.3.2、DC Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
HIGH-level output voltage	V_{OH}	$V_I = V_{T+}$ or V_{T-}	$I_O = -100\mu\text{A}; V_{CC} = 1.65\text{V to } 5.5\text{V}$	$V_{CC} - 0.1$	-	V
			$I_O = -4\text{mA}; V_{CC} = 1.65\text{V}$	0.95	-	V
			$I_O = -8\text{mA}; V_{CC} = 2.3\text{V}$	1.7	-	V
			$I_O = -12\text{mA}; V_{CC} = 2.7\text{V}$	1.9	-	V
			$I_O = -24\text{mA}; V_{CC} = 3.0\text{V}$	2.0	-	V
			$I_O = -32\text{mA}; V_{CC} = 4.5\text{V}$	3.4	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{T+}$ or V_{T-}	$I_O = 100\mu\text{A}; V_{CC} = 1.65\text{V to } 5.5\text{V}$	-	-	0.10 V
			$I_O = 4\text{mA}; V_{CC} = 1.65\text{V}$	-	-	0.70 V
			$I_O = 8\text{mA}; V_{CC} = 2.3\text{V}$	-	-	0.45 V
			$I_O = 12\text{mA}; V_{CC} = 2.7\text{V}$	-	-	0.60 V
			$I_O = 24\text{mA}; V_{CC} = 3.0\text{V}$	-	-	0.80 V
			$I_O = 32\text{mA}; V_{CC} = 4.5\text{V}$	-	-	0.80 V
input leakage current	I_I	$V_I = 5.5\text{V or GND}; V_{CC} = 0\text{V to } 5.5\text{V}$	-	-	± 1	μA
power-off leakage current	I_{OFF}	V_I or $V_O = 5.5\text{V}; V_{CC} = 0\text{V}$	-	-	± 2	μA
supply current	I_{CC}	$V_I = 5.5\text{V or GND}; I_O = 0\text{A}; V_{CC} = 1.65\text{V to } 5.5\text{V}$	-	-	4	μA
additional supply current	ΔI_{CC}	$V_I = V_{CC} - 0.6\text{V}; I_O = 0\text{A}; V_{CC} = 2.3\text{V to } 5.5\text{V}$	-	-	500	μA

3.3.3、AC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ. ^[1]	Max.	Unit
nA to nY propagation delay	t_{PLH}	see Figure 5	$V_{CC} = 1.65\text{V to } 1.95\text{V}$	-	14	ns
			$V_{CC} = 2.3\text{V to } 2.7\text{V}$	-	10	ns
			$V_{CC} = 2.7\text{V}$	-	9	ns
			$V_{CC} = 3.0\text{V to } 3.6\text{V}$	-	8	ns
			$V_{CC} = 4.5\text{V to } 5.5\text{V}$	-	7	ns
nA to nY propagation delay	t_{PHL}	see Figure 5	$V_{CC} = 1.65\text{V to } 1.95\text{V}$	-	12.5	ns
			$V_{CC} = 2.3\text{V to } 2.7\text{V}$	-	11	ns
			$V_{CC} = 2.7\text{V}$	-	11	ns
			$V_{CC} = 3.0\text{V to } 3.6\text{V}$	-	11	ns
			$V_{CC} = 4.5\text{V to } 5.5\text{V}$	-	10	ns

Note:

[1] Typical values are measured at $T_{amb} = 25^{\circ}\text{C}$ and $V_{CC} = 1.8\text{V}, 2.5\text{V}, 2.7\text{V}, 3.3\text{V}$ and 5.0V respectively.

3.3.4、AC Characteristics 2

($T_{amb}=-40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ. ^[1]	Max.	Unit
nA to nY propagation delay	t_{PLH}	see Figure 5	$V_{CC}=1.65\text{V to }1.95\text{V}$	-	-	23 ns
			$V_{CC}=2.3\text{V to }2.7\text{V}$	-	-	17 ns
			$V_{CC}=2.7\text{V}$	-	-	15.5 ns
			$V_{CC}=3.0\text{V to }3.6\text{V}$	-	-	14 ns
			$V_{CC}=4.5\text{V to }5.5\text{V}$	-	-	12.5 ns
nA to nY propagation delay	t_{PHL}	see Figure 5	$V_{CC}=1.65\text{V to }1.95\text{V}$	-	-	20.8 ns
			$V_{CC}=2.3\text{V to }2.7\text{V}$	-	-	18.5 ns
			$V_{CC}=2.7\text{V}$	-	-	18.5 ns
			$V_{CC}=3.0\text{V to }3.6\text{V}$	-	-	18.5 ns
			$V_{CC}=4.5\text{V to }5.5\text{V}$	-	-	17 ns

Note:

[1] Typical values are measured at $T_{amb}=25^{\circ}\text{C}$ and $V_{CC}=1.8\text{V}, 2.5\text{V}, 2.7\text{V}, 3.3\text{V}$ and 5.0V respectively.

3.3.5、Transfer Characteristics 1

($T_{amb}=-40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
positive-going threshold voltage	V_{T+}	see Figure 6 and Figure 7	$V_{CC}=1.8\text{V}$	0.82	1.02	1.2 V
			$V_{CC}=2.3\text{V}$	1.03	1.25	1.45 V
			$V_{CC}=3.0\text{V}$	1.29	1.5	1.71 V
			$V_{CC}=4.5\text{V}$	1.84	2.15	2.41 V
			$V_{CC}=5.5\text{V}$	2.19	2.6	2.91 V
negative-going threshold voltage	V_{T-}	see Figure 6 and Figure 7	$V_{CC}=1.8\text{V}$	0.45	0.6	0.75 V
			$V_{CC}=2.3\text{V}$	0.64	0.8	0.96 V
			$V_{CC}=3.0\text{V}$	0.86	1.1	1.34 V
			$V_{CC}=4.5\text{V}$	1.35	1.75	2.09 V
			$V_{CC}=5.5\text{V}$	1.61	2.15	2.59 V
hysteresis voltage	V_H	$(V_{T+} - V_{T-});$ see Figure 6 and Figure 7	$V_{CC}=1.8\text{V}$	-	0.4	- V
			$V_{CC}=2.3\text{V}$	-	0.4	- V
			$V_{CC}=3.0\text{V}$	-	0.42	- V
			$V_{CC}=4.5\text{V}$	-	0.45	- V
			$V_{CC}=5.5\text{V}$	-	0.47	- V

3.3.6、Transfer Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
positive-going threshold voltage	V _{T+}	see Figure 6 and Figure 7	V _{CC} =1.8V	0.79	-	1.2	V
			V _{CC} =2.3V	1.00	-	1.45	V
			V _{CC} =3.0V	1.26	-	1.71	V
			V _{CC} =4.5V	1.81	-	2.41	V
			V _{CC} =5.5V	2.16	-	2.91	V
negative-going threshold voltage	V _{T-}	see Figure 6 and Figure 7	V _{CC} =1.8V	0.45	-	0.78	V
			V _{CC} =2.3V	0.64	-	0.99	V
			V _{CC} =3.0V	0.86	-	1.37	V
			V _{CC} =4.5V	1.35	-	2.12	V
			V _{CC} =5.5V	1.61	-	2.62	V
hysteresis voltage	V _H	(V _{T+} - V _{T-}); see Figure 6 and Figure 7	V _{CC} =1.8V	-	0.4	-	V
			V _{CC} =2.3V	-	0.4	-	V
			V _{CC} =3.0V	-	0.42	-	V
			V _{CC} =4.5V	-	0.45	-	V
			V _{CC} =5.5V	-	0.47	-	V

4、Testing Circuit

4.1、AC Testing Circuit

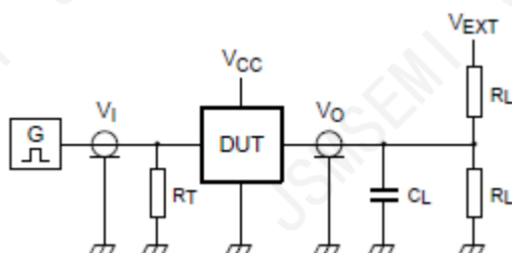


Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

R_L =Load resistance.

C_L =Load capacitance including jig and probe capacitance.

R_T =Termination resistance; should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} =External voltage for measuring switching times.

4.2、AC Testing Waveforms

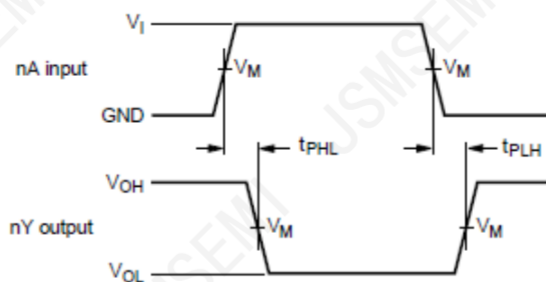


Figure 5. The input nA to output nY propagation delays

4.3、Transfer Characteristics Waveforms

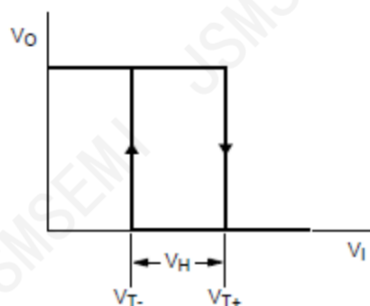


Figure 6. Transfer characteristic

V_{T+} and V_{T-} limits at 70% and 20%:

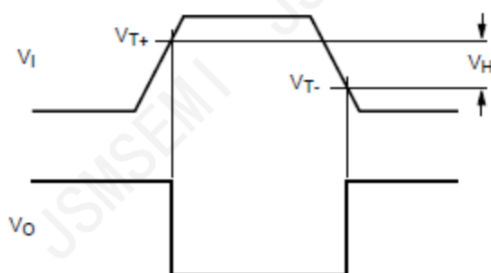


Figure 7. Definition of V_{T+} , V_{T-} and V_H

4.4、Measurement Points

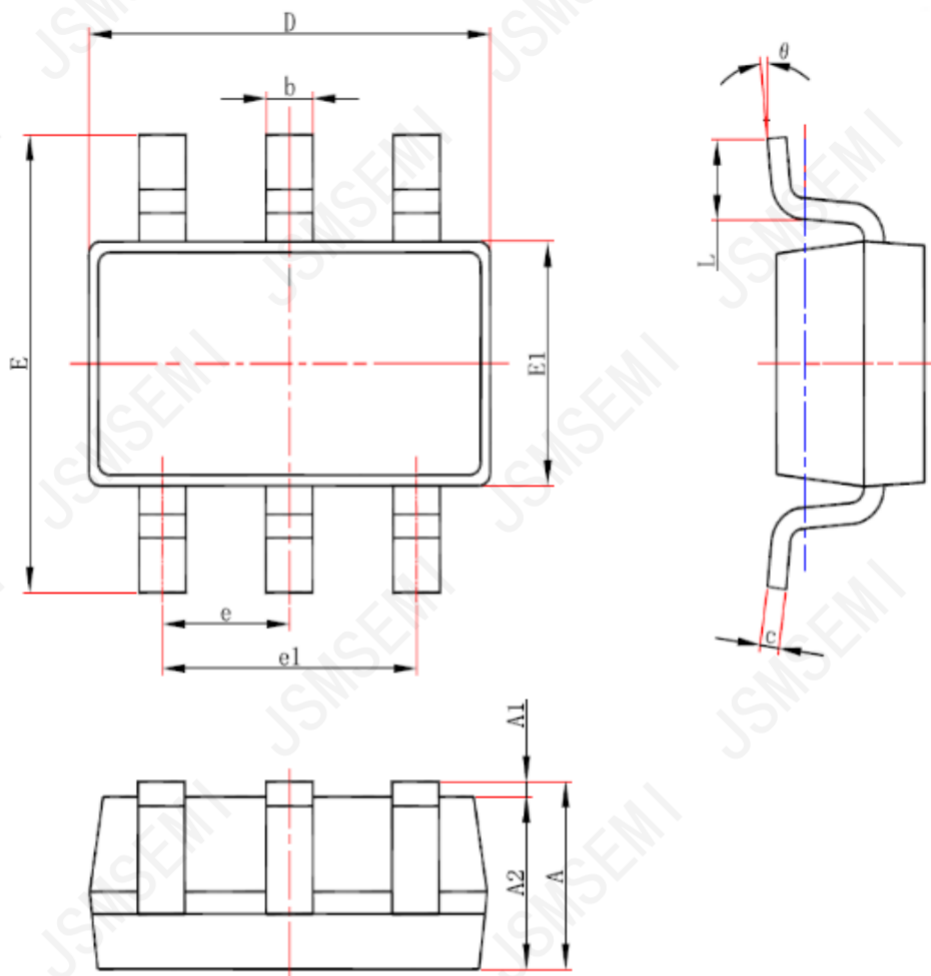
Supply voltage	Input	Output
V_{CC}	V_M	V_M
1.65V to 1.95V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.3V to 2.7V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.7V	1.5V	1.5V
3.0V to 3.6V	1.5V	1.5V
4.5V to 5.5V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$

4.5、Test Data

Supply voltage	Input		Load		V_{EXT}
V_{CC}	V_I	$t_r = t_f$	C_L	R_L	t_{PLH}, t_{PHL}
1.65V to 1.95V	V_{CC}	$\leq 3ns$	30pF	1k Ω	open
2.3V to 2.7V	V_{CC}	$\leq 3ns$	30pF	500 Ω	open
2.7V	2.7V	$\leq 3ns$	50pF	500 Ω	open
3.0V to 3.6V	2.7V	$\leq 3ns$	50pF	500 Ω	open
4.5V to 5.5V	V_{CC}	$\leq 3ns$	50pF	500 Ω	open

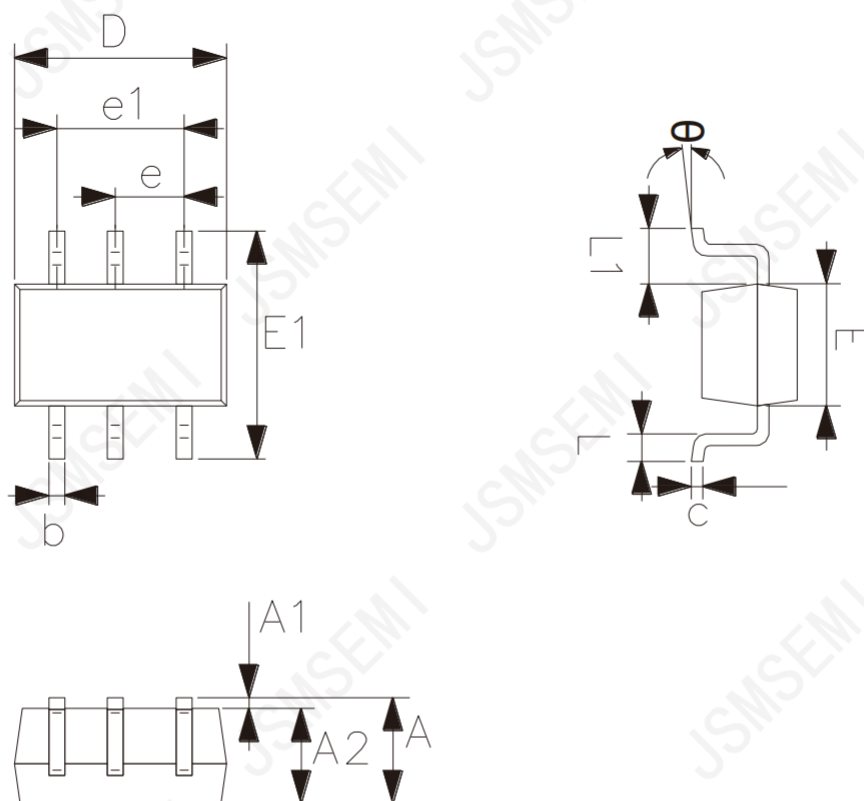
5、Package Information

5.1、SOT-23-6



Symbol	Dimensions (mm)	
	Min.	Max.
A	-	1.25
A1	0.00	0.12
A2	1.00	1.20
b	0.30	0.50
c	0.10	0.20
D	2.82	3.02
E	2.60	3.00
E1	1.50	1.70
e	0.95	
e1	1.80	2.00
L	0.30	0.60
θ	0°	8°

5.2、SOT-363



Symbol	Dimensions (mm)	
	Min.	Max.
A	0.90	1.10
A1	0.00	0.10
A2	0.90	1.00
b	0.15	0.35
c	0.11	0.175
D	2.00	2.20
E1	2.15	2.45
E	1.15	1.35
e	0.65	
e1	1.20	1.40
L	0.26	0.46
L1	0.525	
θ	0°	8°

6、Statements And Notes

6.1、The name and content of Hazardous substances or Elements in the product

Part name	Hazardous substances or Elements									
	Lead and lead compounds	Mercury and mercury compounds	Cadmium and cadmium compounds	Hexavalent chromium compounds	Polybrominated biphenyls	Polybrominated biphenyl ethers	Dibutyl phthalate	Butylbenzyl phthalate	Di-2-ethylhexyl phthalate	Diisobutyl phthalate
Lead frame	○	○	○	○	○	○	○	○	○	○
Plastic resin	○	○	○	○	○	○	○	○	○	○
Chip	○	○	○	○	○	○	○	○	○	○
The lead	○	○	○	○	○	○	○	○	○	○
Plastic sheet installed	○	○	○	○	○	○	○	○	○	○
explanation	○: Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. ×: Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements.									